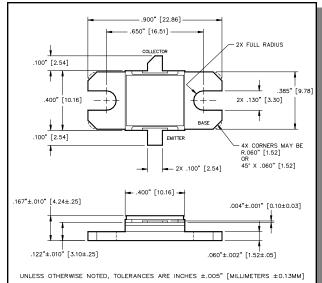
# **Radar Pulsed Power Transistor** 20W, 3.1-3.4 GHz, 300µs Pulse, 10% Duty

#### Features

- NPN silicon microwave power transistors •
- Common base configuration
- Broadband Class C operation •
- High efficiency inter-digitized geometry •
- Diffused emitter ballasting resistors •
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- **RoHS** compliant

## **Outline Drawing**



#### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V <sub>CES</sub>	65	V
Emitter-Base Voltage	V <sub>EBO</sub>	3.0	V
Collector Current (Peak)	Ι <sub>C</sub>	2.4	А
Power Dissipation @ +25°C	P <sub>TOT</sub>	146	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	TJ	200	°C

#### Electrical Specifications: T<sub>c</sub> = 25 ± 5°C (Room Ambient )

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA		BV <sub>CES</sub>	65	-	V
Collector-Emitter Leakage Current	$V_{CE} = 40V$		I <sub>CES</sub>	-	1.5	mA
Thermal Resistance	Vcc = 36V, Pout = 20W	F = 3.1, 3.25, 3.4 GHz	R <sub>TH(JC)</sub>	-	1.2	°C/W
Input Power	Vcc = 36V, Pout = 20W	F = 3.1, 3.25, 3.4 GHz	P <sub>IN</sub>	-	3.56	W
Power Gain	Vcc = 36V, Pout = 20W	F = 3.1, 3.25, 3.4 GHz	G <sub>P</sub>	7.5	-	dB
Collector Efficiency	Vcc = 36V, Pout = 20W	F = 3.1, 3.25, 3.4 GHz	η <sub>c</sub>	35	-	%
Input Return Loss	Vcc = 36V, Pout = 20W	F = 3.1, 3.25, 3.4 GHz	RL	-	-6	dB
Load Mismatch Tolerance	Vcc = 36V, Pout = 20W	F = 3.1, 3.25, 3.4 GHz	VSWR-T	-	2:1	-

1

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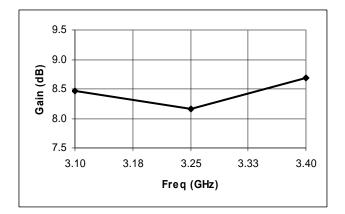
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20W, 3.1-3.4 GHz, 300µs Pulse, 10% Duty

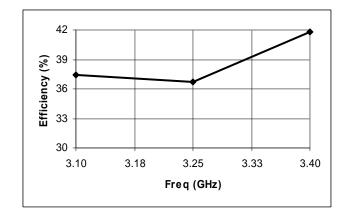
#### Typical RF Performance

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	lc (A)	Eff (%)	RL (dB)	VSWR-T (2:1)
3.10	2.85	20.0	8.47	1.49	37.4	-9.6	-
3.25	3.05	20.0	8.17	1.52	36.7	-10.7	Р
3.40	2.71	20.0	8.68	1.33	41.8	-15.8	-

Gain vs. Frequency

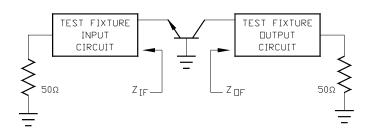


### **Collector Efficiency vs. Frequency**



#### **RF Test Fixture Impedance**

F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
3.10	16.0 + j5.0	19.0 + j3.0
3.25	14.5 + j2.0	15.5 - j2.0
3.40	11.5 + j0.0	10.0 - j3.5



2

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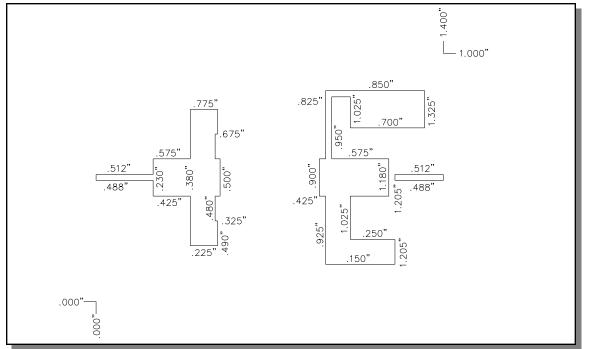
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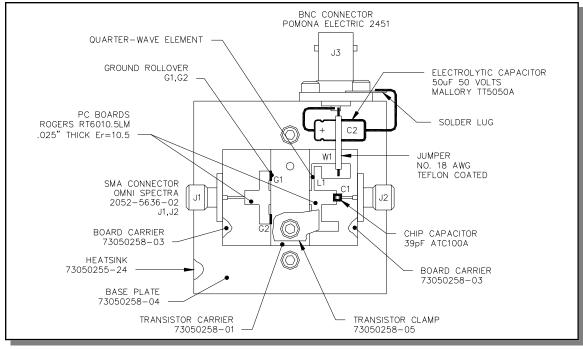
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## **Test Fixture Circuit Dimensions**



### **Test Fixture Assembly**



3

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